

## 15C02CH — NPN Epitaxial Planar Silicon Transistor

### Low-Frequency General-Purpose Amplifier Applications

#### Applications

- Low-frequency amplifier, high-speed switching, small motor drive

#### Features

- Large current capacity
- Low collector-to-emitter saturation voltage (resistance)  $R_{CE(sat)}$  typ.=300m $\Omega$  [ $I_C=1A$ ,  $I_B=50mA$ ]
- Ultrasmall package facilitates miniaturization in end products
- Small ON-resistance ( $R_{on}$ )

#### Specifications

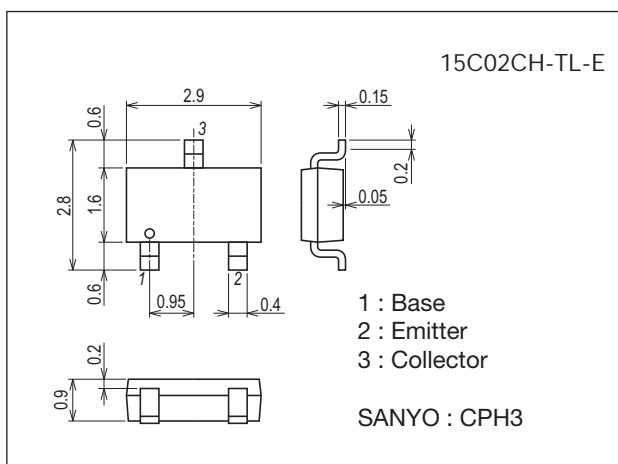
##### Absolute Maximum Ratings at $T_a=25^\circ C$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	$V_{CBO}$		20	V
Collector-to-Emitter Voltage	$V_{CEO}$		15	V
Emitter-to-Base Voltage	$V_{EBO}$		5	V
Collector Current	$I_C$		1	A
Collector Current (Pulse)	$I_{CP}$		2	A
Collector Dissipation	$P_C$	Mounted on a ceramic board (600mm <sup>2</sup> ×0.8mm)	700	mW
Junction Temperature	$T_j$		150	$^\circ C$
Storage Temperature	$T_{stg}$		-55 to +150	$^\circ C$

#### Package Dimensions

unit : mm (typ)

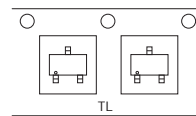
7015A-003



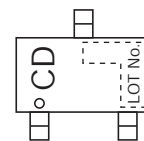
#### Product & Package Information

- Package : CPH3
- JEITA, JEDEC : SC-59, TO-236, SOT-23
- Minimum Packing Quantity : 3,000 pcs./reel

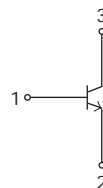
#### Packing Type: TL



#### Marking



#### Electrical Connection

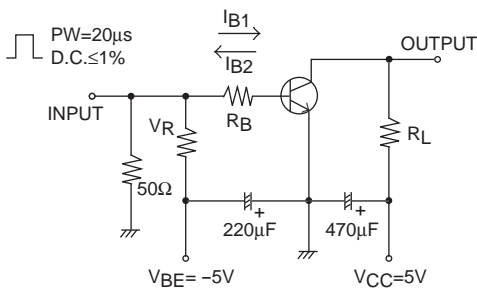


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## Electrical Characteristics at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	$I_{CBO}$	$V_{CB}=12\text{V}, I_E=0\text{A}$			100	nA
Emitter Cutoff Current	$I_{EBO}$	$V_{EB}=4\text{V}, I_C=0\text{A}$			100	nA
DC Current Gain	$h_{FE}$	$V_{CE}=2\text{V}, I_C=50\text{mA}$	300		800	
Gain-Bandwidth Product	$f_T$	$V_{CE}=2\text{V}, I_C=50\text{mA}$		400		MHz
Output Capacitance	$C_{ob}$	$V_{CB}=10\text{V}, f=1\text{MHz}$		4		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=400\text{mA}, I_B=20\text{mA}$		140	280	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=400\text{mA}, I_B=20\text{mA}$		0.9	1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\mu\text{A}, I_E=0\text{A}$	20			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=1\text{mA}, R_{BE}=\infty$	15			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=10\mu\text{A}, I_C=0\text{A}$	5			V
Turn-On Time	$t_{on}$	See specified Test Circuit.		30		ns
Storage Time	$t_{stg}$			165		ns
Fall Time	$t_f$			25		ns

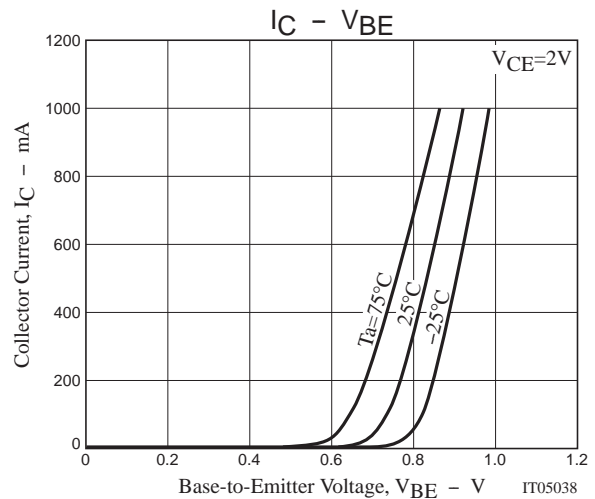
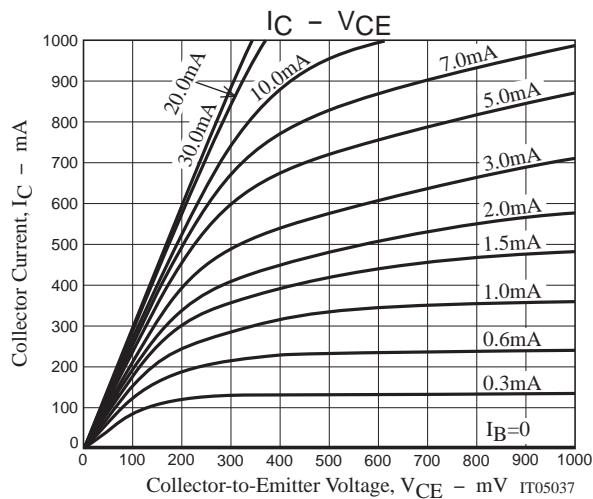
## Switching Time Test Circuit

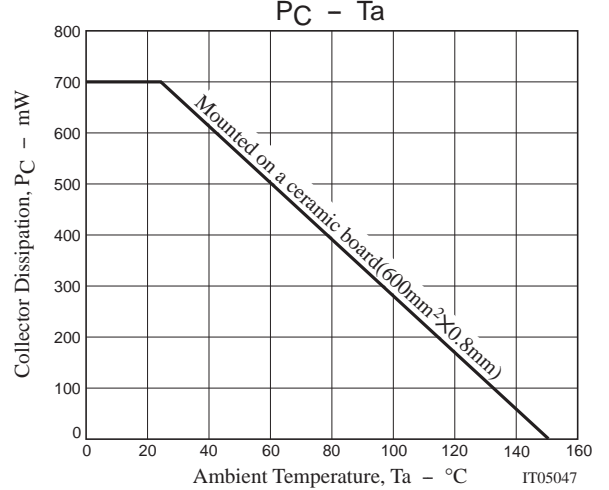
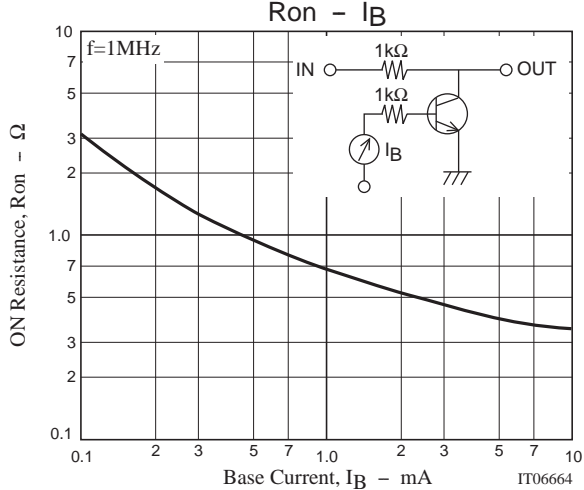
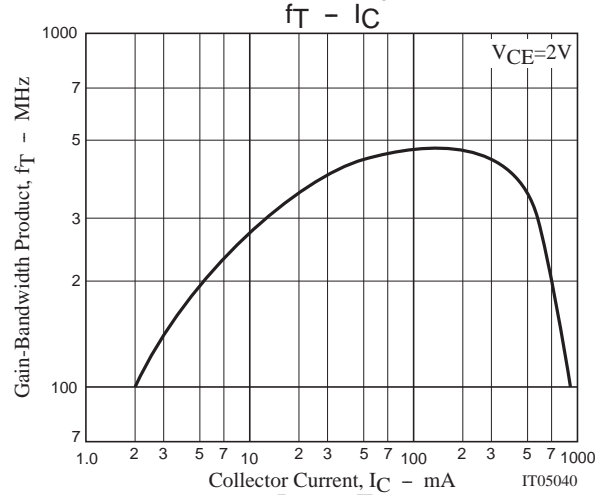
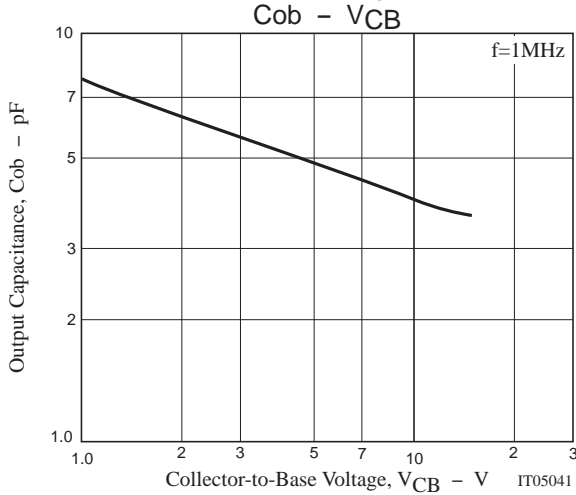
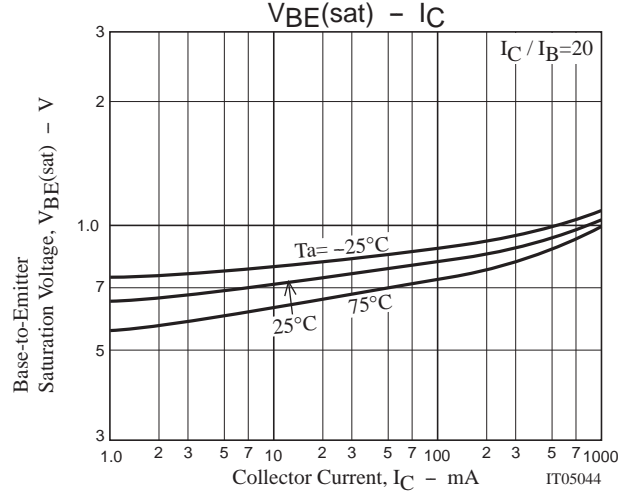
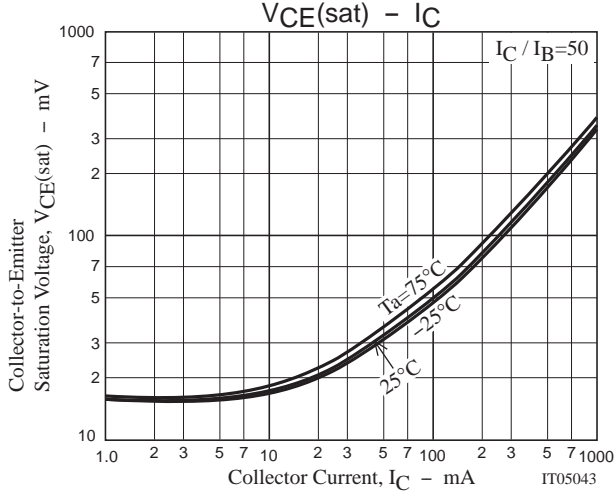
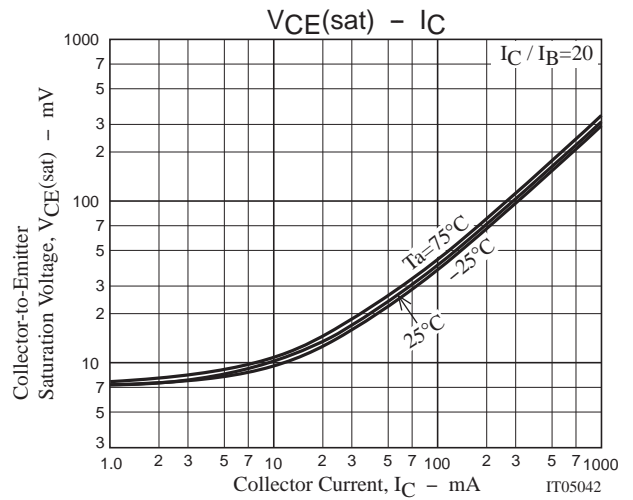
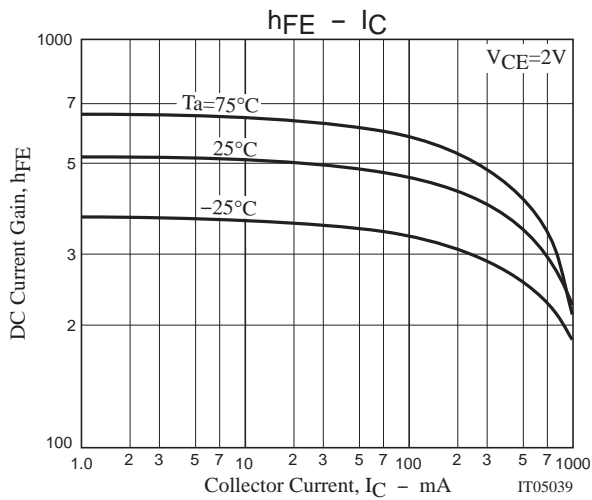


$$I_C = 20I_{B1} = -20I_{B2} = 400\text{mA}$$

## Ordering Information

Device	Package	Shipping	memo
15C02CH-TL-E	CPH3	3,000pcs./reel	Pb Free





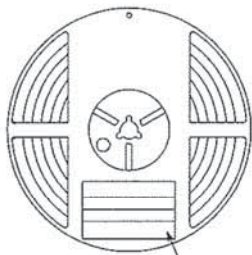
Embossed Taping Specification

15C02CH-TL-E

1. Packing Format

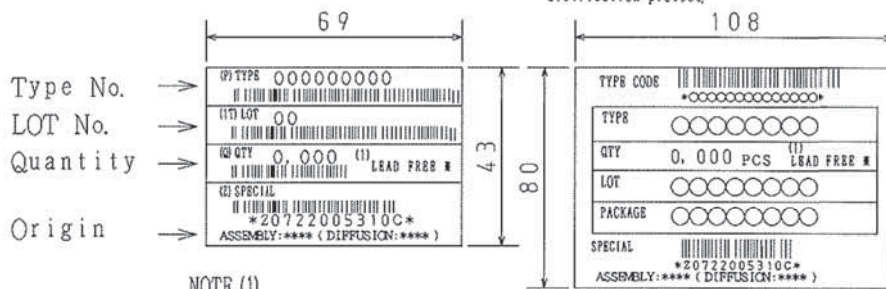
Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
CPH3	CPH3	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Packing method



Reel label

Reel label, Inner box label (unit:mm)



It is a label at the time of factory shipments. The form of a label may change in physical distribution process.

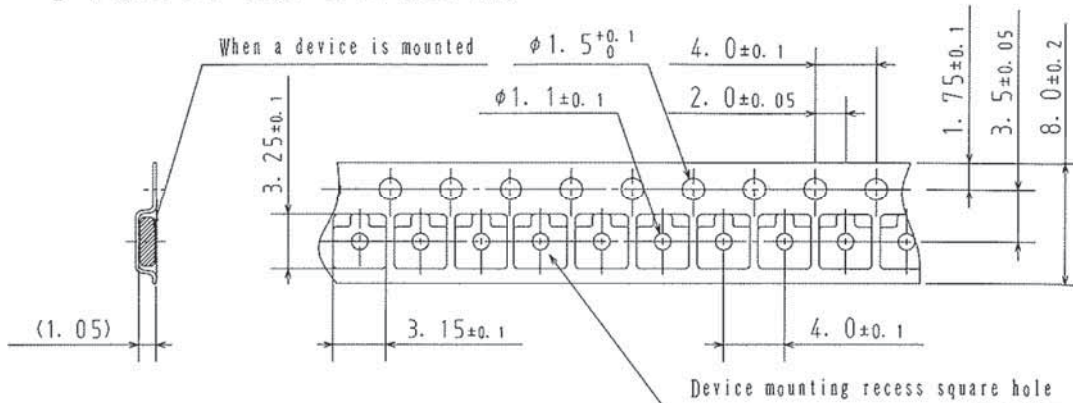
NOTE (1)

The LEAD FREE # description shows that the surface treatment of the terminal is lead free.

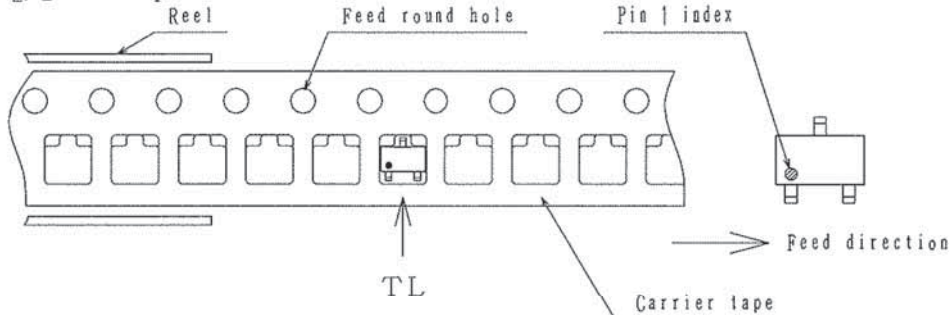
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction

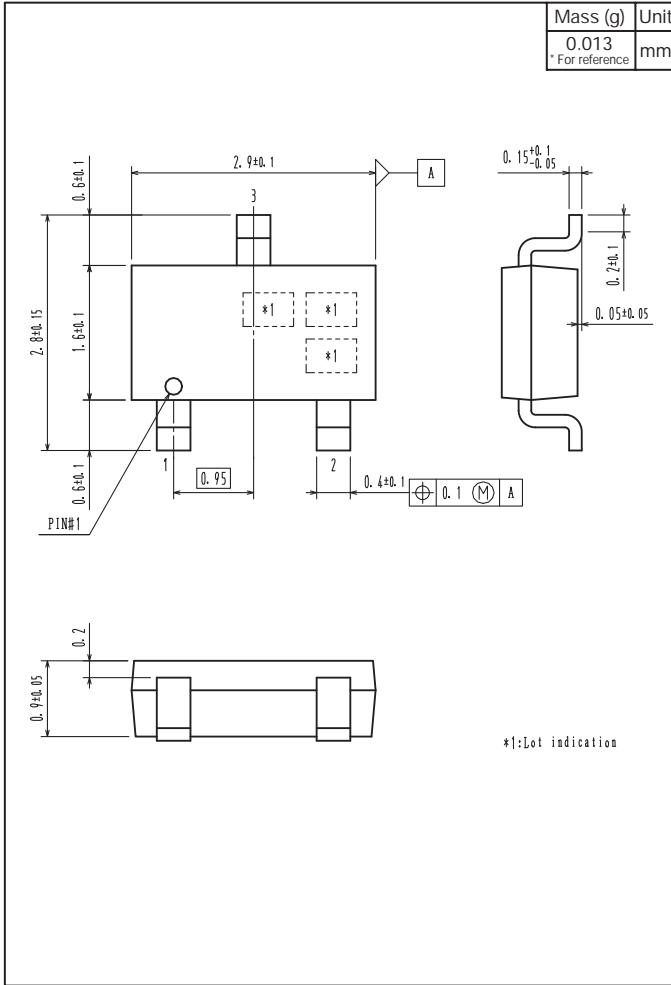


Those with one electrode terminal on the feed hole side.....TL

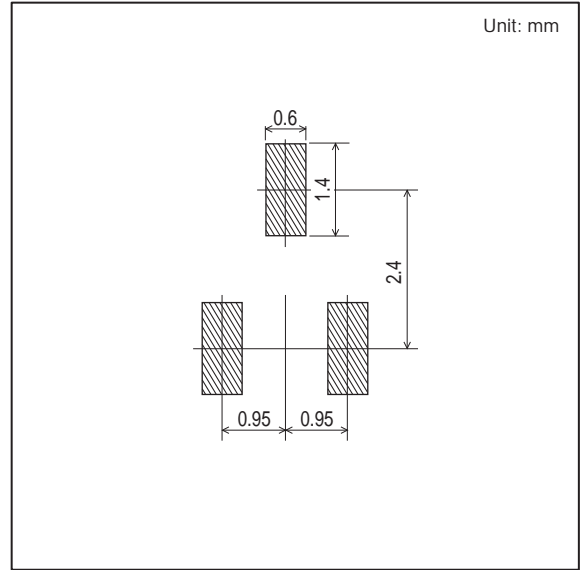
# 15C02CH

## Outline Drawing

15C02CH-TL-E



## Land Pattern Example



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